

## 1-Line, Bi-directional, Transient Voltage Suppressors

### Descriptions

The ESD5D200TA is a bi-directional TVS (Transient Voltage Suppressor). It is specifically designed to protect sensitive electronic components that may be subjected to ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning. It is particularly well-suited for cellular phones, portable device, digital cameras, power supplies and many other portable applications because of its small package and low weight.

The ESD5D200TA is available in DFN1006-2L package. Standard products are Pb-free and Halogen-free.



**DFN1006-2L**



**Circuit diagram**

### Features

- Stand-off voltage:  $\pm 5V$  Max
- Transient protection for each line according to IEC61000-4-2 (ESD):  $\pm 30KV$  Air,  $\pm 30KV$  contact IEC61000-4-5 (Surge): 18A (8/20 $\mu s$ )
- Solid-state silicon technology
- Low leakage current

### Order information

| Device     | Marking | Package    | Shipping        |
|------------|---------|------------|-----------------|
| ESD5D200TA | H       | DFN1006-2L | 10000/Tape&Reel |

### Applications

- Cell phone handsets and accessories
- Personal Digital Assistants (PDAs)
- Notebooks, Desktops, and Servers
- Portable Instrumentation
- Digital Cameras
- CAR/MID DVD/MP3/MP4/PMP Players

## Absolute maximum ratings

| Parameter                                       | Symbol    | Rating   | Unit        |
|-------------------------------------------------|-----------|----------|-------------|
| Peak pulse current ( $t_p = 8/20\mu s$ )        | $I_{pp}$  | 18.0     | A           |
| ESD according to IEC61000-4-2 air discharge     | $V_{ESD}$ | $\pm 30$ | kV          |
| ESD according to IEC61000-4-2 contact discharge |           | $\pm 30$ |             |
| Operating temperature                           | $T_{OP}$  | -40~125  | $^{\circ}C$ |
| Lead temperature                                | $T_L$     | 260      | $^{\circ}C$ |
| Storage temperature                             | $T_{STG}$ | -55~150  | $^{\circ}C$ |

## Electrical characteristics (TA=25 $^{\circ}C$ , unless otherwise noted)

| Parameter                      | Symbol      | Condition                                            | Min. | Typ. | Max.      | Unit     |
|--------------------------------|-------------|------------------------------------------------------|------|------|-----------|----------|
| Reverse stand-off voltage      | $V_{RWM}$   |                                                      |      |      | $\pm 5.0$ | V        |
| Reverse leakage current        | $I_R$       | $V_{RWM} = 5V$                                       |      |      | 0.5       | $\mu A$  |
| Reveres breakdown voltage      | $V_{BR}$    | $I_T = 1mA$                                          | 6.0  |      | 9.0       | V        |
| ESD Clamping Voltage           | $V_{Clamp}$ | IEC 61000-4-2 6kV, Contact mode, $T = 25^{\circ}C$ . |      | 6.5  |           | V        |
| ESD Dynamic Turn-on Resistance | $R_{ds}$    | IEC 61000-4-2 6kV, Contact mode, $T = 25^{\circ}C$ . |      | 0.02 |           | $\Omega$ |
| Clamping voltage               | $V_C$       | $I_{pp} = 1A$ $t_p = 8/20\mu s$                      |      |      | 6.0       | V        |
|                                |             | $I_{pp} = 18A$ $t_p = 8/20\mu s$                     |      | 8.2  | 9.5       | V        |
| Junction capacitance           | $C_J$       | $V_R = 0V$ , $f = 1MHz$                              |      | 25.0 | 40.0      | pF       |

## Electrical performance curve

$V_{RWM}$  Reverse stand-off voltage

$I_R$  Reverse leakage current

$V_{CL}$  Clamping voltage

$I_{PP}$  Peak pulse current

$V_{TRIG}$  Reverse trigger voltage

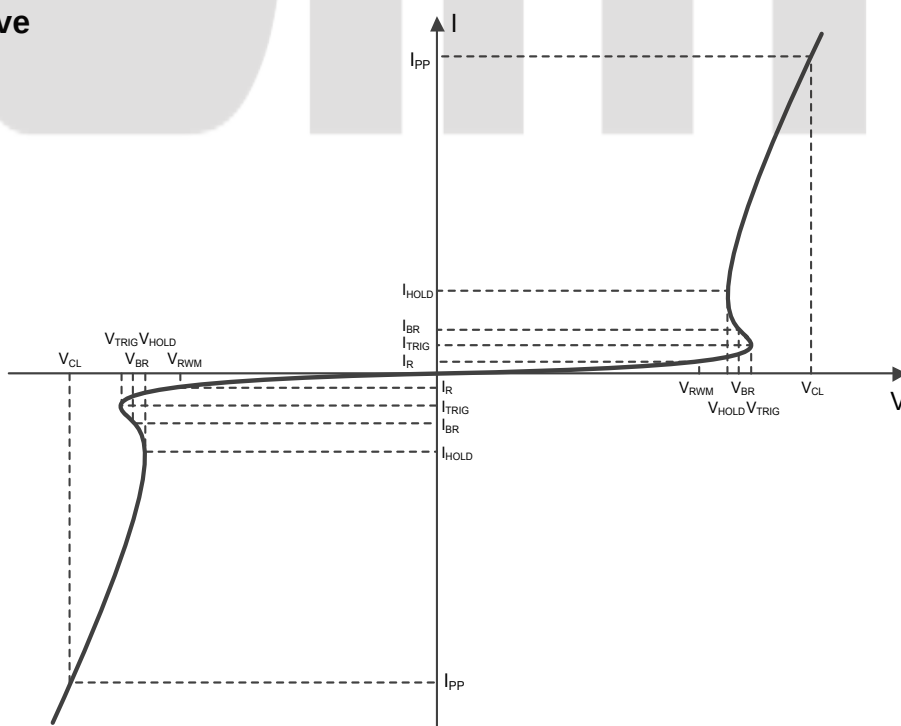
$I_{TRIG}$  Reverse trigger current

$V_{BR}$  Reverse breakdown voltage

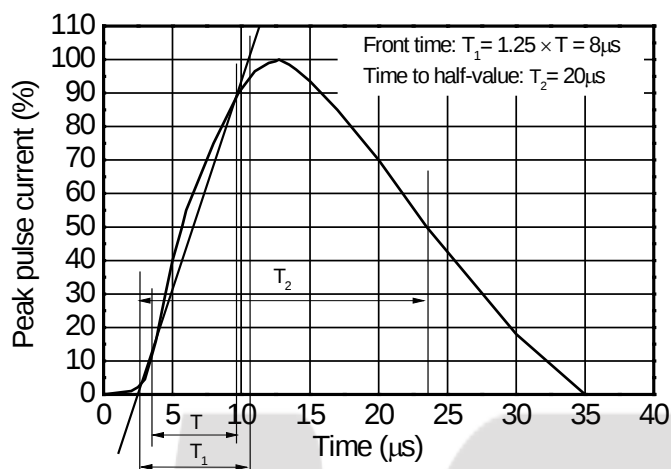
$I_{BR}$  Reverse breakdown current

$V_{HOLD}$  Reverse holding voltage

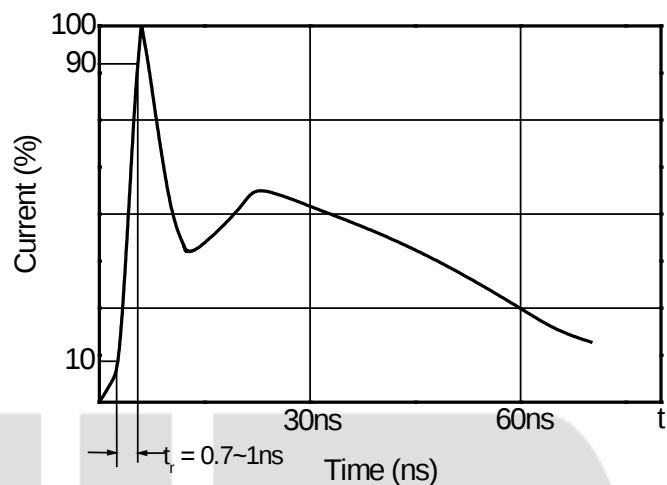
$I_{HOLD}$  Reverse holding current



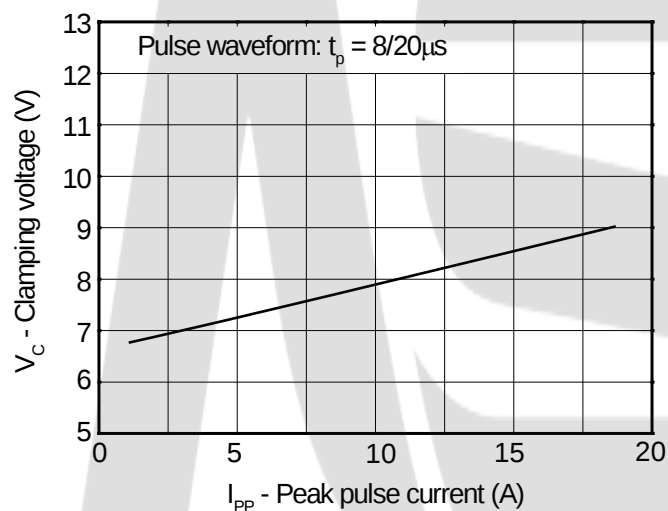
Typical characteristics ( $T_A=25^\circ\text{C}$ , unless otherwise noted)



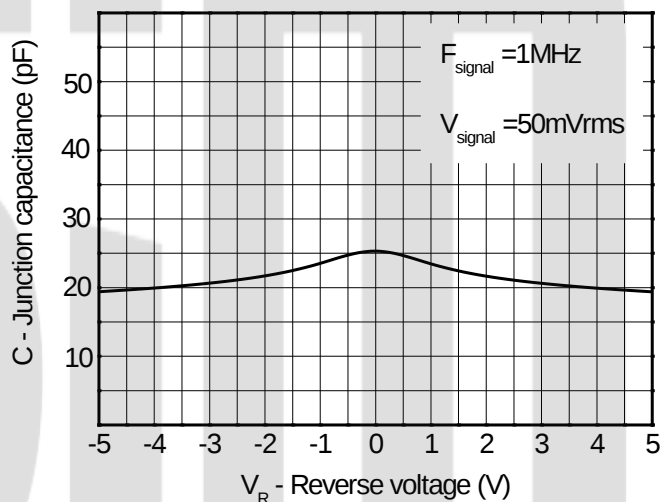
8/20 $\mu\text{s}$  waveform per IEC61000-4-5



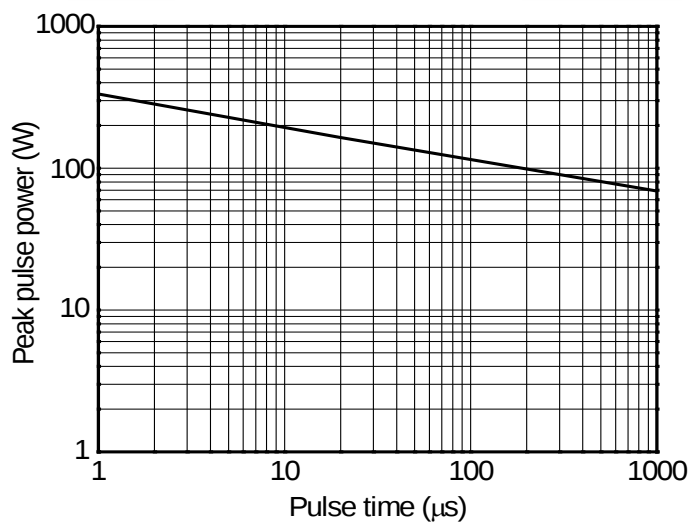
Contact discharge current waveform per IEC61000-4-2



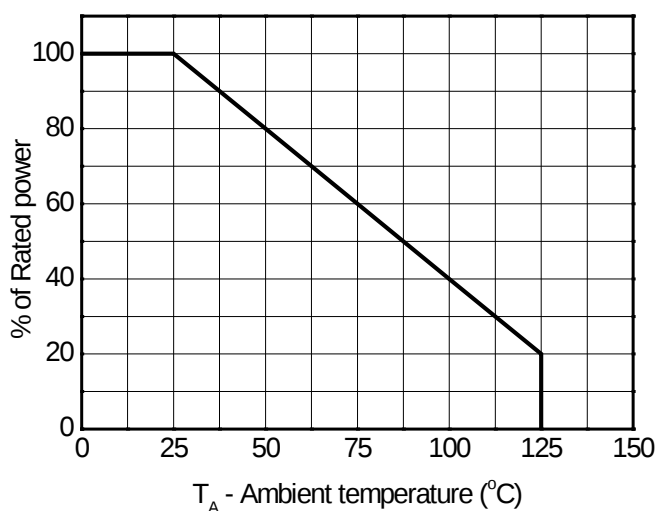
Clamping voltage vs. Peak pulse current



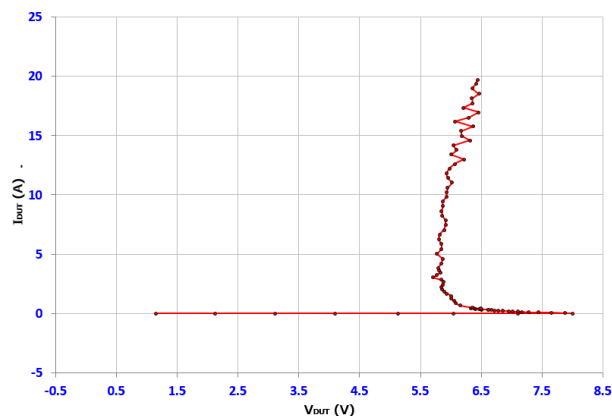
Capacitance vs. Reverse voltage



Non-repetitive peak pulse power vs. Pulse time

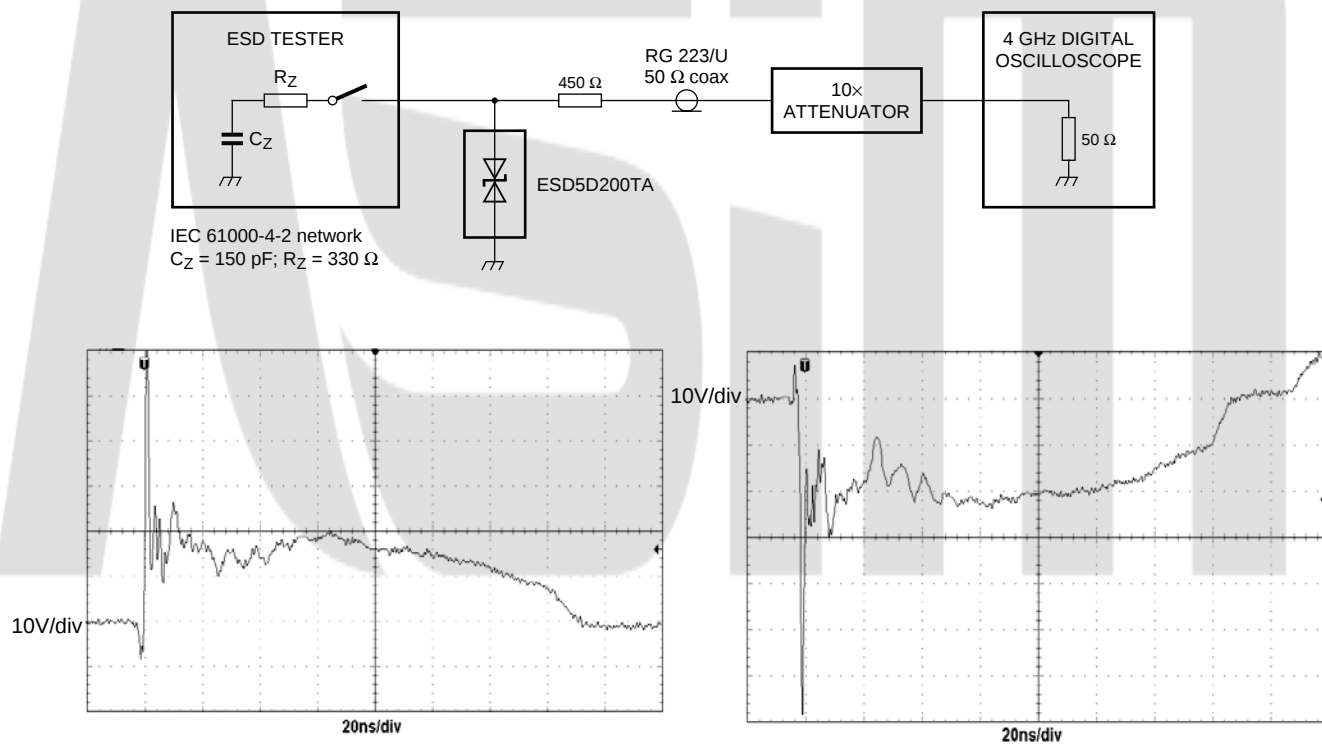


Power derating vs. Ambient temperature



Transmission Line Pulsing (TLP) Voltage (V)

## ESD clamping test setup and waveforms



**ESD clamping**  
(+8kV contact discharge per IEC61000-4-2)

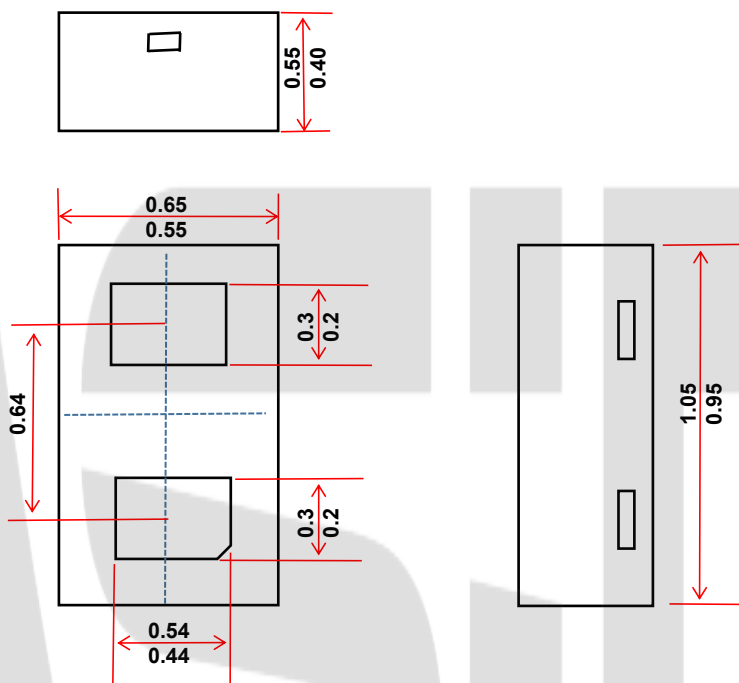
**ESD clamping**  
(-8kV contact discharge per IEC61000-4-2)

## Package outline dimensions

### DFN1006-2L

DIMENSION OUTLINE:

Unit:mm



## Recommended Mounting Pad Layout

Unit:mm

